
T-1 3/4 (5 mm) Precision Optical Performance InGaN Blue and Green LEDs

Technical Data

SunPower Series

HLMP-CB15 **HLMP-CM15**
HLMP-CB16 **HLMP-CM16**
HLMP-CB30 **HLMP-CM30**
HLMP-CB31 **HLMP-CM31**

Features

- **Smooth, Consistent Spatial Radiation Patterns**
- **Viewing Angles: 15° and 30°**
- **High Luminous Output**
- **Colors: 472 nm Blue, 526 nm Green**
- **Superior Resistance to Moisture**

Benefits

- **Superior Performance in Outdoor Environments**
- **Wavelengths Suitable for Color Mixing in Full Color (RGB) Signs**
- **Color to Color Consistency of Radiation Patterns (CBxx to CMxx to HLMP-EGxx Red) Enables Sign Color Uniformity at All Angles**

Applications

- **Commercial Outdoor Signs**
- **Automotive Interior Lights**
- **Front Panel Indicators**
- **Front Panel Backlighting**

Description

These high intensity blue and green LEDs are based on InGaN material technology. InGaN is the most efficient and cost effective material for LEDs in the blue and green region of the spectrum. The 472 nm typical dominant wavelength for blue and 526 nm typical dominant wavelength for green are well suited to color mixing in full color signs.

These LED lamps are untinted, nondiffused, T-1 3/4 packages incorporating second generation optics producing well defined spatial radiation patterns at specific viewing cone angles.

These lamps are made with an advanced optical grade epoxy, offering superior temperature and moisture resistance in outdoor signal and sign applications. The high maximum



LED junction temperature limit of +130°C enables high temperature operation in bright sunlight conditions. The package epoxy contains both UV-a and UV-b inhibitors to reduce the effects of long term exposure to direct sunlight.

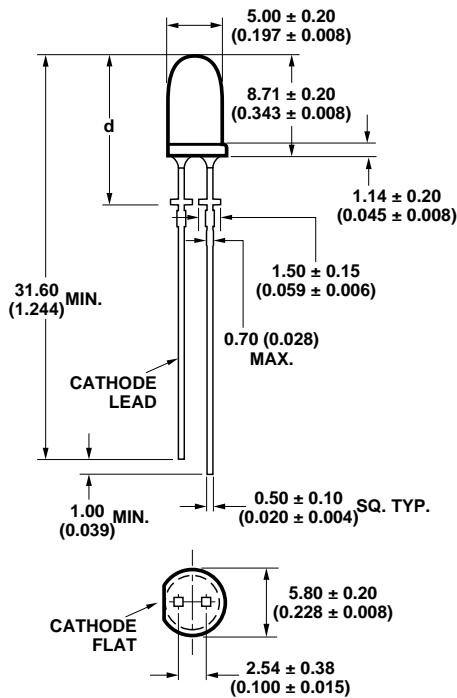
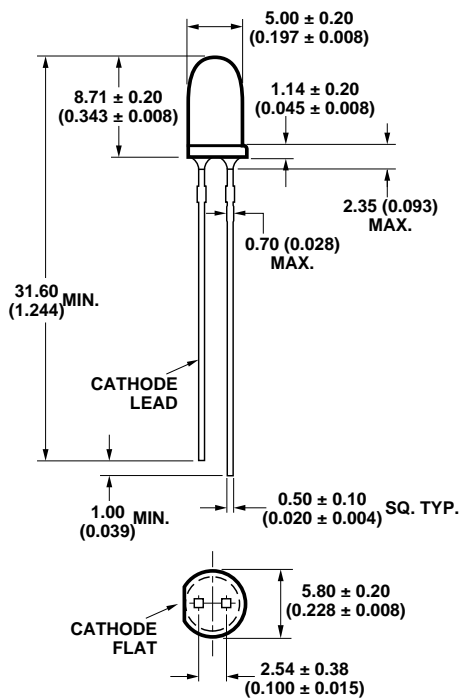
These lamps are available in two viewing angle options and two package options to give the designer flexibility with optical design and device mounting.

CAUTION: HLMP-CBxx LEDs and -CMxx's are Class 1 ESD sensitive. Please observe appropriate precautions during handling and processing. Refer to Agilent Application Note AN-1142 for additional details.

Device Selection Guide

Part Number	Color	Viewing Angle	Typical Intensity at 20 mA (mcd)	Stand Off
HLMP-CB15	Blue	15°	1575	No
HLMP-CB16	Blue	15°	1575	Yes
HLMP-CB30	Blue	30°	560	No
HLMP-CB31	Blue	30°	560	Yes
HLMP-CM15	Green	15°	4700	No
HLMP-CM16	Green	15°	4700	Yes
HLMP-CM30	Green	30°	1750	No
HLMP-CM31	Green	30°	1750	Yes

Package Dimensions



Notes:

- Dimensions in mm.
- Tolerance ± 0.1 mm unless otherwise noted.

HLMP-Cx16	HLMP-Cx31
$d = 12.60 \pm 0.25$ (0.496 \pm 0.010)	$d = 11.96 \pm 0.25$ (0.471 \pm 0.010)

Absolute Maximum Ratings at $T_A = 25^\circ\text{C}$

Parameter	Value	Units
DC Forward Current ^[1]	30	mA
Peak Forward Current	100	mA
Average Forward Current	30	mA
Power Dissipation	120	mW
Reverse Voltage ($I_R = 100 \mu\text{A}$)	5	V
LED Junction Temperature	130	$^\circ\text{C}$
Operating Temperature Range	-40 to +80	$^\circ\text{C}$
Storage Temperature Range	-40 to +100	$^\circ\text{C}$

Note:

- Derate linearly as shown in Figure 4 for temperatures above 50°C .

Optical Characteristics at $T_A = 25^\circ\text{C}$

Part Number	Luminous Intensity $I_V^{[1]}$ (mcd) at $I_F = 20\text{ mA}$		Peak Wavelength λ_{PEAK} (nm) Typ.	Color, Dominant Wavelength $\lambda_d^{[2]}$ (nm) Typ.	Spectral Halfwidth $\Delta\lambda_{1/2}$ (nm)	Viewing Angle $2\theta_{1/2}$ Degrees ^[3] Typ.	Luminous Efficacy ^[4] η_V (lm/W)
	Min.	Typ.					
HLMP-CB15/16	765	1575	470	472	35	15	75
HLMP-CB30/31	270	560	470	472	35	30	75
HLMP-CM15/16	1650	4700	524	526	47	15	520
HLMP-CM30/31	765	1750	524	526	47	30	520

Notes:

1. All InGaN LEDs represented here are IEC825 Class 2. See *Application Brief 1009* and *1015* for details.
2. The dominant wavelength λ_d is derived from the CIE Chromaticity Diagram and represents the perceived color of the device.
3. $\theta_{1/2}$ is the off-axis angle where the luminous intensity is 1/2 the peak intensity.
4. Luminous efficacy is the ratio of luminous flux to radiant flux.

Electrical Characteristics at $T_A = 25^\circ\text{C}$

Forward Voltage V_F (Volts) at $I_F = 20\text{ mA}$		Reverse Breakdown V_R (Volts) at $I_R = 100\ \mu\text{A}$ Min.	Capacitance C (pF), $V_F = 0$, $f = 1\text{ MHz}$ Typ.	Thermal Resistance $R\theta_{J-PIN}$ ($^\circ\text{C/W}$)
Typ.	Max.			
3.8	4.0	5	43	240

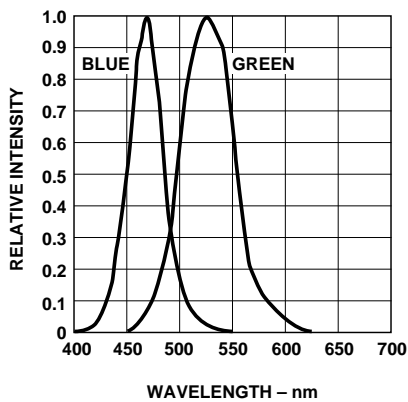


Figure 1. Relative Intensity vs. Wavelength.

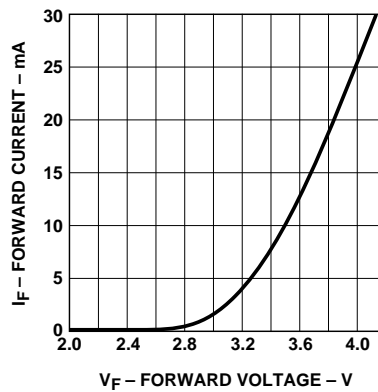


Figure 2. Forward Current vs. Forward Voltage.

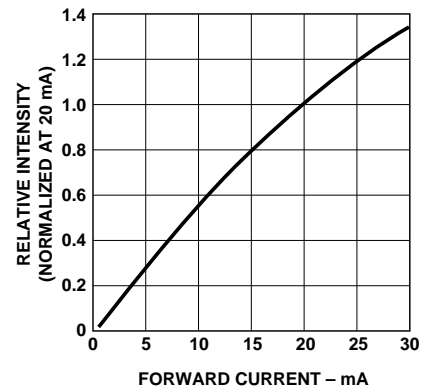


Figure 3. Relative Luminous Intensity vs. Forward Current.

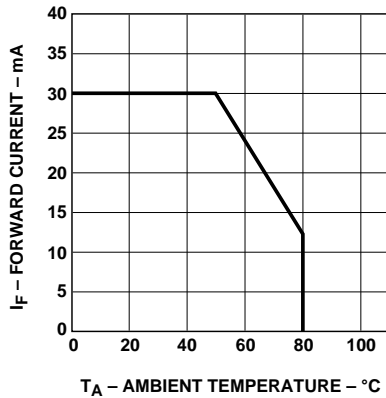


Figure 4. Maximum Forward Current vs. Ambient Temperature.

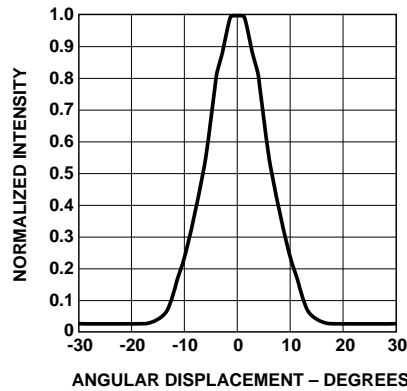


Figure 5. Spatial Radiation Pattern – 15° Lamps.

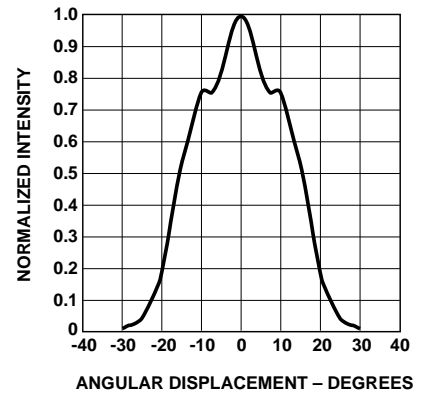


Figure 6. Spatial Radiation Pattern – 30° Lamps.

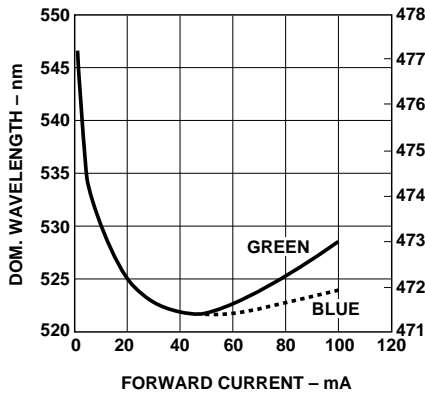


Figure 7. Color vs. Forward Current.

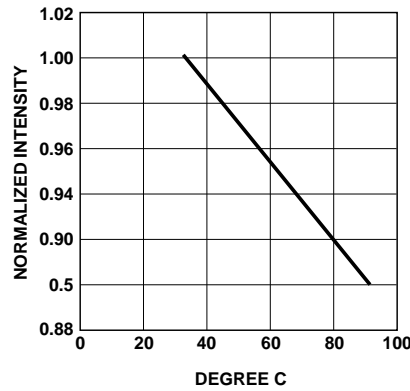


Figure 8. Normalized I_v vs. T (Green).

Color Bin Limits (nm at 20 mA)

Blue		
Bin ID	Min.	Max.
1	460.0	464.0
2	464.0	468.0
3	468.0	472.0
4	472.0	476.0
5	476.0	480.0

Tolerance for each bin limit will be ± 2 nm.

Green		
Bin ID	Min.	Max.
3	520.0	525.0
4	525.0	530.0
5	530.0	535.0
6	535.0	540.0

Intensity Bin Limits (mcd @ 20 mA)		
Bin Name	Min.	Max.
K	310	400
L	400	520
M	520	680
N	680	880
P	880	1150
Q	1150	1500
R	1500	1900
T	2500	3200
U	3200	4200
V	4200	5500
W	5500	7200

Tolerance of each minimum and maximum = $\pm 15\%$.

For product information and a complete list of distributors, please go to our web site.

www.agilent.com/semiconductors

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Data subject to change.

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Obsoletes 5988-2249EN

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